

Amendments to the Claims

1. (Currently Amended) An amplifier comprising:

a front amplification stage that includes a first transistor; and

a rear amplification stage which amplifies an output signal of said front amplification stage, said rear amplification stage being disposed immediately after said front amplification stage, said rear amplification stage including a plurality of amplification unit units connected in parallel, said plurality of amplification units include rear stage transistors; and

a rear stage DC bias control circuit which controls a bias of a second transistor, which is one of the rear stage transistors, according to an input level of an RF signal,
wherein

~~amplification unit that forms a part of one of the plurality of amplification unit perform units performs~~ on/off switching of amplification operation according to [[an]] the RF input of the front amplification stage or increase a bias current as the RF input increases,and

said rear stage DC bias control circuit is connected between an emitter of the first transistor and a base of the second transistor and the second transistor is supplied with a bias controlled by said rear stage DC bias control circuit.

2. (Currently Amended) An amplifier comprising:

a front stage transistor supplied with an RF signal;

an inter-stage matching circuit;

a rear stage transistor group having a plurality of transistors connected in parallel and supplied with an output signal of said front stage transistor via said inter-stage matching circuit; and

a rear stage DC bias control circuit which controls a bias of a transistor that forms a part of said rear stage transistor group according to an input level of the RF signal,
wherein said rear stage DC bias control circuit is connected between an emitter of said front stage transistor and a base of a transistor included in said rear stage transistor group and supplied with a bias controlled by said rear stage DC bias control circuit.

3. (Cancelled)

4. (Withdrawn) The amplifier according to claim 3, wherein said rear stage DC bias control circuit comprises AC blocking inductors connected in series between the emitter and the base, and a hunt resistor.

5. (Currently Amended) The amplifier according to claim [[3]] 2, wherein said rear stage DC bias control circuit comprises an AC blocking inductor and a resistor connected in series between the emitter and the base, and a shunt resistor.

6. (Withdrawn) The amplifier according to claim 3, wherein said rear state DC bias control circuit includes resistors connected in series between the emitter and the base, and a shunt resistor.

7. (Withdrawn) The amplifier according to claim 3, wherein said rear stage DC bias control circuit includes an AC blocking inductor and a resistor connected in series between the emitter and the base, and a shunt diode.

8. (Withdrawn) The amplifier according to claim 3, wherein said rear stage DC bias control circuit includes resistors connected in series between the emitter and the base, and a shunt diode.

9. (Currently Amended) [[The]] An amplifier according to claim 2 comprising:
a front stage transistor supplied with an RF signal;
an inter-stage matching circuit;
a rear stage transistor group having a plurality of transistors connected in parallel
and supplied with an output signal of said front stage transistor via said inter-stage
matching circuit; and

a rear stage DC bias control circuit which controls a bias of a transistor that forms
a part of said rear stage transistor group according to an input level of the RF signal,
wherein

 said rear stage DC bias control circuit is connected between a source of said
front stage transistor and a gate of a transistor included in said rear stage transistor
group and supplied with a bias controlled by said rear stage DC bias control circuit.

10. (Withdrawn) The amplifier according to claim 9, wherein said rear stage DC bias control circuit includes AC blocking inductors connected in series between the source and the gate, and a shunt resistor.

11. (Original) The amplifier according to claim 9, wherein said rear stage DC bias control circuit includes an AC blocking inductor and a resistor connected in series between the source and the gate, and a shunt resistor.

12. (Withdrawn) The amplifier according to claim 9, wherein said rear stage DC bias control circuit includes resistors connected in series between the source and the gate, and a shunt resistor.

13. (Withdrawn) The amplifier according to claim 9, wherein said rear stage DC bias control circuit includes an AC blocking inductor and a resistor connected in series between the source and the gate, and a shunt diode.

14. (Withdrawn) The amplifier according to claim 9, wherein said rear stage DC bias control circuit includes resistors connected in series between the source and the gate, and a shunt diode.

15. (Withdrawn) The amplifier according to claim 2, wherein said rear stage DC bias control circuit includes a control transistor supplied with the RF signal, and said

control transistor controls a bias of a transistor that forms a part of said rear stage transistor group according to an input level of the RF signal.

16. (Withdrawn) The amplifier according to claim 15, wherein said front group transistor, a transistor included in the rear transistor group and supplied with a fixed bias, and said control transistor are biased so as to perform operation of class AB.

17. (Withdrawn) The amplifier according to claim 15, wherein said rear stage DC bias control circuit further includes AC blocking inductors connected in series between an emitter of said control transistor and a base of a transistor included in said rear stage transistor group and supplied with a bias controlled by said rear stage DC bias control circuit, and a shunt resistor.

18. (Withdrawn) The amplifier according to claim 15, wherein said rear stage DC bias control circuit further includes an AC blocking inductor and a resistor connected in series between an emitter of said control transistor and a base of a transistor included in said rear stage transistor group and supplied with a bias controlled by said rear stage DC bias control circuit, and a shunt resistor.

19. (Withdrawn) The amplifier according to claim 15, wherein said rear stage DC bias control circuit further includes resistors connected in series between an emitter of said control transistor and a base of a transistor included in said rear stage transistor

group and supplied with a bias controlled by said rear stage DC bias control circuit, and a shunt resistor.

20. (Withdrawn) The amplifier according to claim 15, wherein said rear stage DC bias control circuit further includes an AC blocking inductor and a resistor connected in series between an emitter of said control transistor and a base of a transistor included in said rear stage transistor group and supplied with a bias controlled by said rear stage DC bias control circuit, and a shunt diode.

21. (Withdrawn) The amplifier according to claim 15, wherein said rear stage DC bias control circuit further includes resistors connected in series between an emitter of said control transistor and a base of a transistor included in said rear stage transistor group and supplied with a bias controlled by said rear stage DC bias control circuit, and a shunt diode.

22. (Withdrawn) The amplifier according to claim 15, wherein said rear stage DC bias control circuit further includes AC blocking inductors connected in series between a source of said control transistor and a gate of a transistor included in said rear stage transistor group and supplied with a bias controlled by said rear stage DC bias control circuit, and a shunt resistor.

23. (Withdrawn) The amplifier according to claim 15, wherein said rear stage DC bias control circuit further includes an AC blocking inductor and a resistor connected in series between a source of said control transistor and a gate of a transistor included in said rear stage transistor group and supplied with a bias controlled by said rear stage DC bias control circuit, and a shunt resistor.

24. (Withdrawn) The amplifier according to claim 15, wherein said rear stage DC bias control circuit further includes resistors connected in series between a source of said control transistor and a gate of a transistor included in said rear stage transistor group and supplied with a bias controlled by said rear stage DC bias control circuit, and a shunt resistor.

25. (Withdrawn) The amplifier according to claim 15, wherein aid rear stage DC bias control circuit further includes an AC blocking inductor and a resistor connected in series between a source of said control transistor and a gate of a transistor included in said rear stage transistor group and supplied with a bias controlled by said rear stage DC bias control circuit, and a shunt diode.

26. (Withdrawn) The amplifier according to claim 15, wherein said rear stage DC bias control circuit further includes resistors connected in series between a source of said control transistor and a gate of a transistor included in said rear stage transistor

group and supplied with a bias controlled by said rear stage DC bias control circuit, and a shunt diode.

27. (Original) The amplifier according to claim 2, wherein said front stage transistor, said inter-stage matching circuit, said rear stage transistor group, and the rear group DC bias control circuit are integrated on same semiconductor chip.

28. (Original) The amplifier according to claim 2, wherein said front stage transistor, said inter-stage matching circuit, said rear stage transistor group, and the rear group DC bias control circuit are provided distributively on two or more semiconductor chips.